



Science & Technology Facilities Council

ASTeC



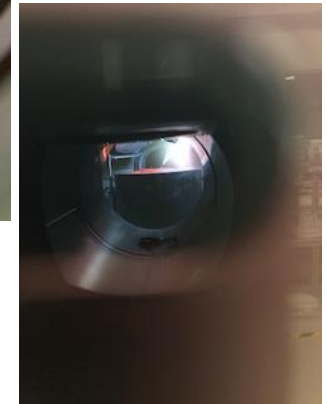
Progress report of SRF thin film deposition and characterisation at ASTeC



SRF Coating

In total four samples have been deposited during the last month.

- Nb/AlN/Nb₃Sn on copper
- Nb₃Sn on LNL EP copper
- Nb₃Sn on DL EP copper
- Nb/Nb₃Sn on copper
- Nb/AlN/Nb₃Sn on sapphire



in all cases the deposition temperature was kept at 650 C and the substrate was heated 18 hours prior to deposition.



Deposition Parameters

- Substrate heated 20 h prior deposition
- deposition temperature 650C



Deposition of Nb and Nb₃Sn was done in DC mode

Deposition of AlN was done pulsed DC with 350 KHz and 1.1 us duty cycle.

Deposition time: 4 h for Nb and 2h for Nb₃N

Deposition SIS: 4 h for Nb, 10 min for AlN and 30 min for Nb₃Sn

Deposition of Nb₃Sn: 3 hours



Copper Surface Characterisation in SUBU electrolyte

1. Degreasing: in NGL 1740 (surfactant from University of Manchester) bath for about 2 hours.
 - 2. Activation: Sulfamic acid ($\text{H}_3\text{NO}_3\text{S}$, 5 g/l) for about 3 minutes in order to increase surface wettability and avoid bubbling formation at the surface.
 - 3. Polishing: 40 minutes "SUBU5", SUBU5 = sulfamic acid ($\text{H}_3\text{NO}_3\text{S}$, 5 g/l), hydrogen peroxide (H_2O_2 , 5% vol), n-butanol (5% vol) and ammonium citrate (1 g/l) at 72°C ($70\text{--}75^\circ\text{C}$) with bath agitation.
 - 4. Pre-rinsing with acid: Sulfamic acid ($\text{H}_3\text{NO}_3\text{S}$, 5 g/l) for about 1 minute, to remove hydrophobic layer.
 - 5. Rinsing with water: demineralized water for about 30 seconds.
 - 6. Spraying with alcohol: ethyl alcohol to enhance drying.
 - 7. Drying with N_2 .
 - 8. Packing in wafer box.





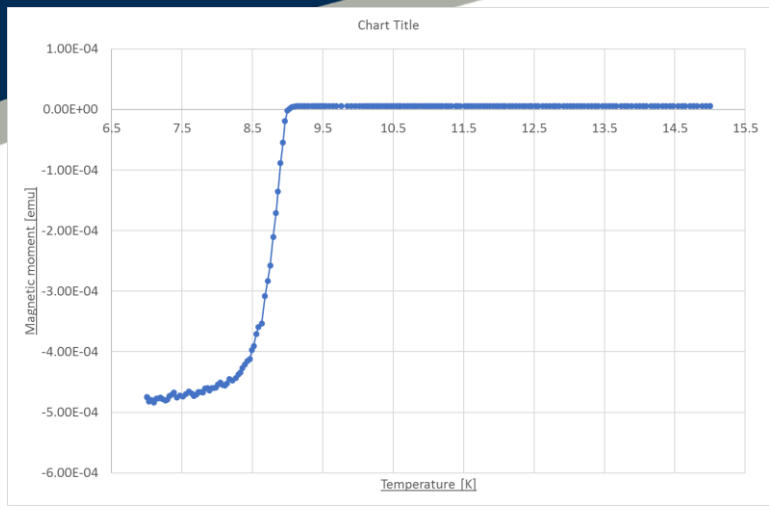
Electro polishing (EP) copper specimen

1. Electrolyte concentration $H_3PO_4/(n)$ butanol (5:1)
2. Applied voltage 4-5 volt, Current density 1 A/cm² in room temperature
Time: 4 hours
3. Rinsing with water: demineralized water for about 30 seconds.
4. Spraying with alcohol: ethyl alcohol to enhance drying.
5. Drying with N₂.
6. Packing in wafer box.

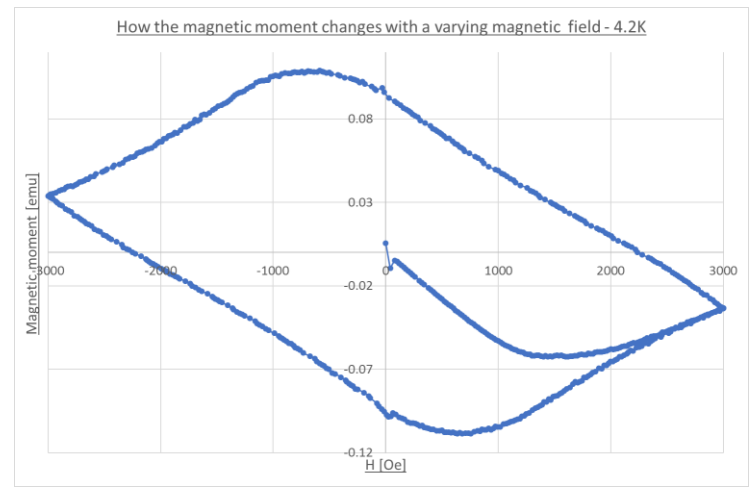




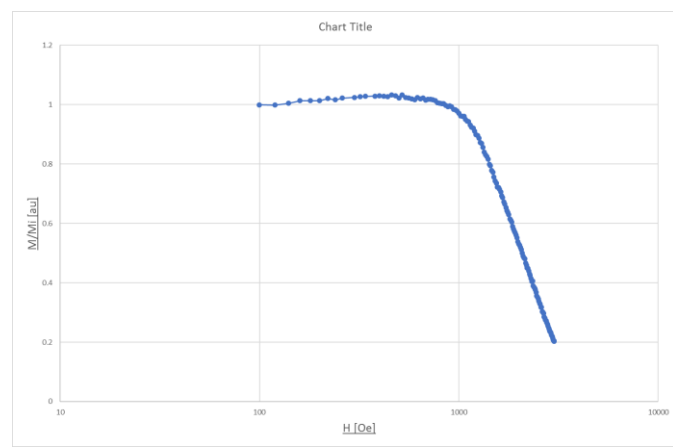
DC Squid for Nb on Ta



Transition phase in 100 Oe field



Hysteresis curve at 4.2 K



Initial magnetisation at 4.2k